



# Schottky Diode

$$V_{RRM} = 180\text{ V}$$

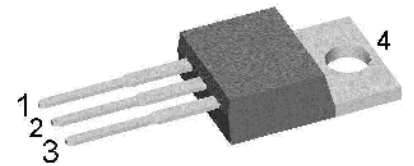
$$I_{FAV} = 2 \times 5\text{ A}$$

$$V_F = 0.6\text{ V}$$

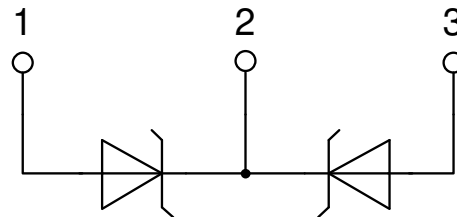
High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

Part number

**DSSK10-018A**



Backside: cathode



**Features / Advantages:**

- Very low  $V_f$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package: TO-220**

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

**Disclaimer Notice**

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

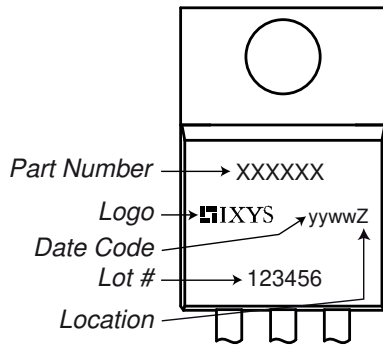


Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					180	V
$V_{RRM}$	max. repetitive reverse blocking voltage					180	V
$I_R$	reverse current, drain current	$V_R = 180\text{ V}$	$T_{VJ} = 25^\circ\text{C}$			300	$\mu\text{A}$
		$V_R = 180\text{ V}$	$T_{VJ} = 125^\circ\text{C}$			2.5	mA
$V_F$	forward voltage drop	$I_F = 5\text{ A}$	$T_{VJ} = 25^\circ\text{C}$			0.76	V
		$I_F = 10\text{ A}$				0.83	V
		$I_F = 5\text{ A}$	$T_{VJ} = 125^\circ\text{C}$			0.60	V
		$I_F = 10\text{ A}$				0.69	V
$I_{FAV}$	average forward current	$T_C = 165^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$			5	A
$V_{F0}$	threshold voltage	} for power loss calculation only				0.43	V
$r_F$	slope resistance					16.6	m $\Omega$
$R_{thJC}$	thermal resistance junction to case					1.7	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.5		K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		90	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$		120	A
$C_J$	junction capacitance	$V_R = 24\text{ V}$ $f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		72	pF



Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal <sup>1)</sup>			35	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				2		g
$M_D$	mounting torque		0.4		0.6	Nm
$F_C$	mounting force with clip		20		60	N

**Product Marking**



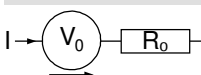
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSSK10-018A	DSSK10-018A	Tube	50	477206

Similar Part	Package	Voltage class
DSSK30-018A	TO-247AD (3)	180
DSA30C200PB	TO-220AB (3)	200

**Equivalent Circuits for Simulation**

*\* on die level*

$T_{VJ} = 175^{\circ}C$

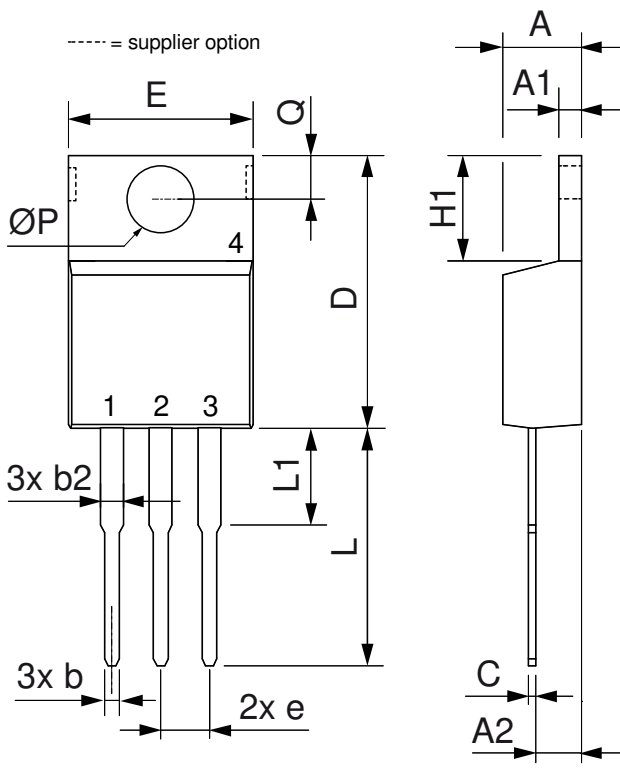


**Schottky**

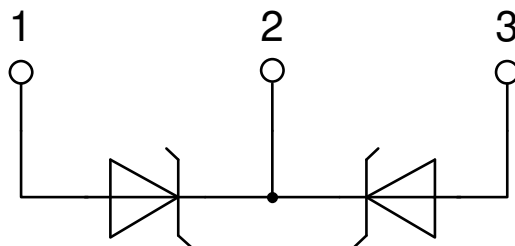
$V_{0\ max}$	threshold voltage	0.43	V
$R_{0\ max}$	slope resistance *	13.4	mΩ



**Outlines TO-220**



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



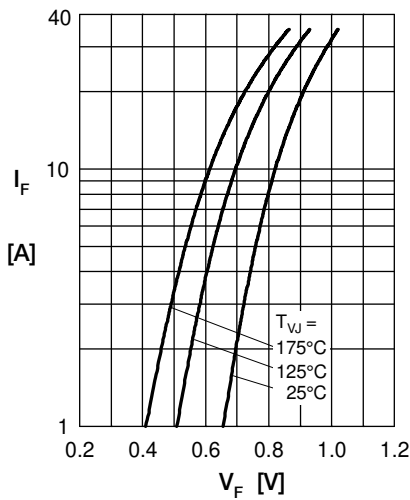
**Schottky**


Fig. 1 Max. forward voltage drop characteristics

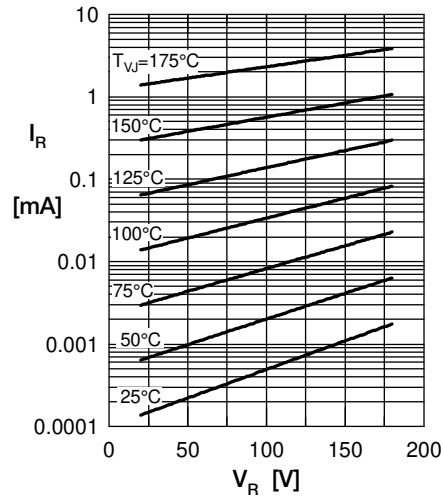
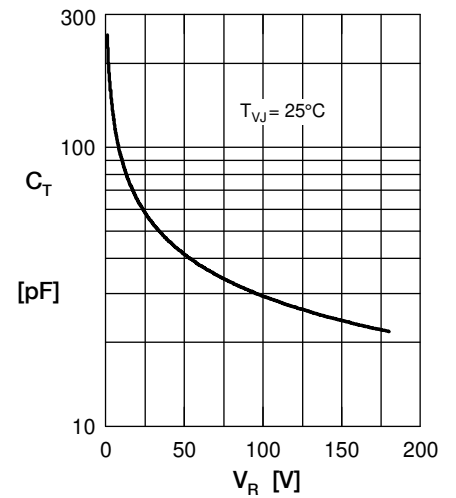
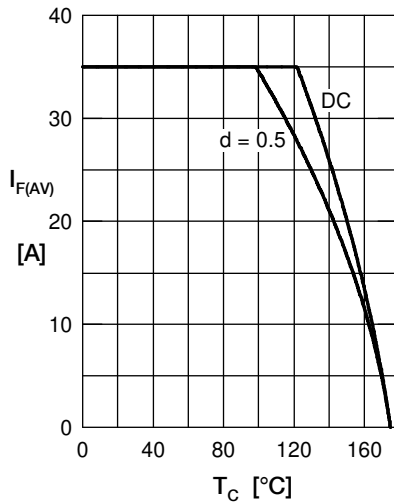
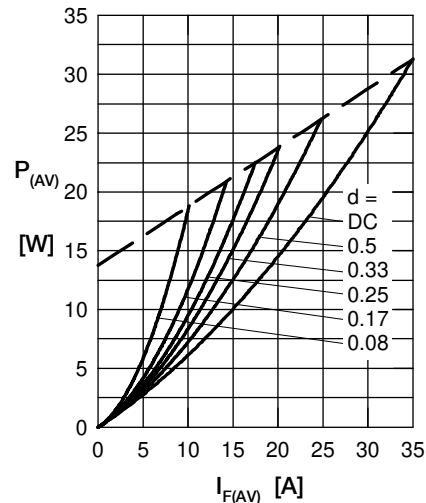

 Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$ 

 Fig. 3 Typ. junction capacitance  $C_T$  vs. reverse voltage  $V_R$ 

 Fig. 4 Average forward current  $I_{F(AV)}$  vs. case temp.  $T_C$ 


Fig. 5 Forward power loss characteristics

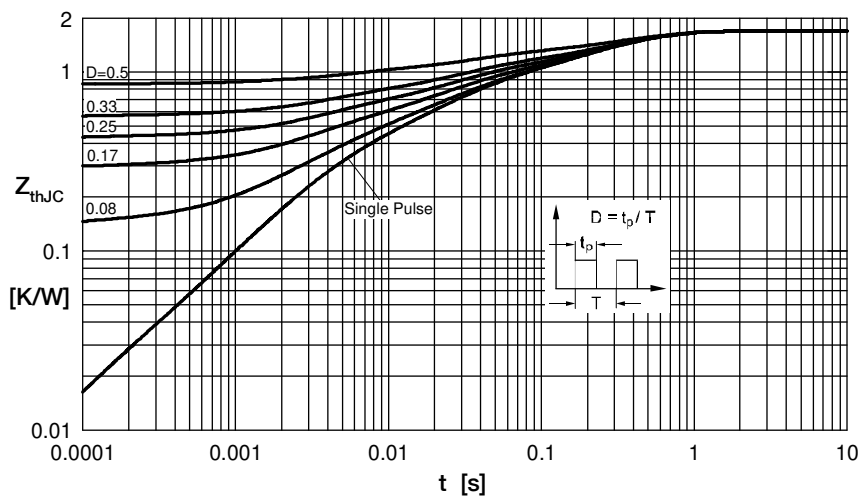


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode